

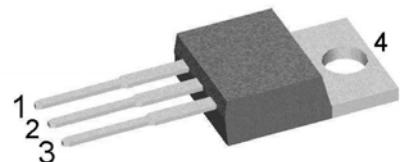
# High Efficiency Thyristor

$V_{RRM}$  = 800V  
 $I_{TAV}$  = 20A  
 $V_T$  = 1.31V

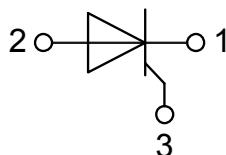
## Single Thyristor

### Part number

CS19-08ho1



Backside: anode



### Features / Advantages:

- Thyristor for line frequency
- Planar passivated chip
- Long-term stability

### Applications:

- Line rectifying 50/60 Hz
- Softstart AC motor control
- DC Motor control
- Power converter
- AC power control
- Lighting and temperature control

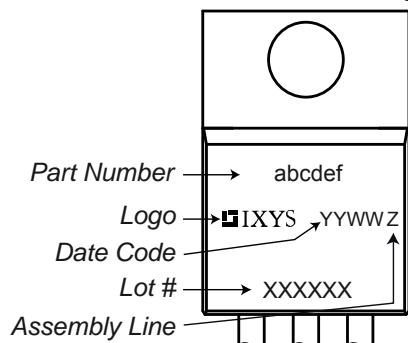
### Package: TO-220

- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0

Thyristor			Ratings			
Symbol	Definition	Conditions	min.	typ.	max.	Unit
$V_{RSM/DSM}$	max. non-repetitive reverse/forward blocking voltage	$T_{VJ} = 25^\circ C$			900	V
$V_{RRM/DRM}$	max. repetitive reverse/forward blocking voltage	$T_{VJ} = 25^\circ C$			800	V
$I_{RD}$	reverse current, drain current	$V_{RD} = 800 V$ $V_{RD} = 800 V$	$T_{VJ} = 25^\circ C$ $T_{VJ} = 125^\circ C$		50 1	$\mu A$ mA
$V_T$	forward voltage drop	$I_T = 20 A$ $I_T = 40 A$ $I_T = 20 A$ $I_T = 40 A$	$T_{VJ} = 25^\circ C$ $T_{VJ} = 125^\circ C$		1.32 1.65 1.31 1.73	V V V V
$I_{TAV}$	average forward current	$T_C = 110^\circ C$	$T_{VJ} = 125^\circ C$		20	A
$I_{T(RMS)}$	RMS forward current	180° sine			31	A
$V_{TO}$ $r_T$	threshold voltage slope resistance } for power loss calculation only		$T_{VJ} = 125^\circ C$		0.86 22	V $m\Omega$
$R_{thJC}$	thermal resistance junction to case				0.7	K/W
$R_{thCH}$	thermal resistance case to heatsink			0.50		K/W
$P_{tot}$	total power dissipation		$T_C = 25^\circ C$		170	W
$I_{TSM}$	max. forward surge current	$t = 10 \text{ ms}; (50 \text{ Hz}), \text{sine}$ $t = 8,3 \text{ ms}; (60 \text{ Hz}), \text{sine}$ $t = 10 \text{ ms}; (50 \text{ Hz}), \text{sine}$ $t = 8,3 \text{ ms}; (60 \text{ Hz}), \text{sine}$	$T_{VJ} = 45^\circ C$ $V_R = 0 V$ $T_{VJ} = 125^\circ C$ $V_R = 0 V$		180 195 155 165	A A
$I^2t$	value for fusing	$t = 10 \text{ ms}; (50 \text{ Hz}), \text{sine}$ $t = 8,3 \text{ ms}; (60 \text{ Hz}), \text{sine}$ $t = 10 \text{ ms}; (50 \text{ Hz}), \text{sine}$ $t = 8,3 \text{ ms}; (60 \text{ Hz}), \text{sine}$	$T_{VJ} = 45^\circ C$ $V_R = 0 V$ $T_{VJ} = 125^\circ C$ $V_R = 0 V$		160 160 120 115	$A^2s$ $A^2s$ $A^2s$ $A^2s$
$C_J$	junction capacitance	$V_R = 230 V$ $f = 1 \text{ MHz}$	$T_{VJ} = 25^\circ C$		9	pF
$P_{GM}$	max. gate power dissipation	$t_p = 30 \mu s$ $t_p = 300 \mu s$	$T_C = 125^\circ C$		5 2.5 0.5	W W W
$P_{GAV}$	average gate power dissipation					
$(di/dt)_{cr}$	critical rate of rise of current	$T_{VJ} = 150^\circ C; f = 50 \text{ Hz}$ repetitive, $I_T = 60 A$ $t_p = 200 \mu s; di_G/dt = 0.15 A/\mu s;$ $I_G = 0.15 A; V_D = \frac{2}{3} V_{DRM}$ non-repet., $I_T = 20 A$			150	$A/\mu s$
$(dv/dt)_{cr}$	critical rate of rise of voltage	$V_D = \frac{2}{3} V_{DRM}$ $R_{GK} = \infty$ ; method 1 (linear voltage rise)	$T_{VJ} = 150^\circ C$		500	$V/\mu s$
$V_{GT}$	gate trigger voltage	$V_D = 6 V$	$T_{VJ} = 25^\circ C$ $T_{VJ} = -40^\circ C$		1.5 2.5	V V
$I_{GT}$	gate trigger current	$V_D = 6 V$	$T_{VJ} = 25^\circ C$ $T_{VJ} = -40^\circ C$		28 50	mA mA
$V_{GD}$	gate non-trigger voltage	$V_D = \frac{2}{3} V_{DRM}$	$T_{VJ} = 150^\circ C$		0.2	V
$I_{GD}$	gate non-trigger current				3	mA
$I_L$	latching current	$t_p = 10 \mu s$ $I_G = 0.1 A; di_G/dt = 0.1 A/\mu s$	$T_{VJ} = 25^\circ C$		75	mA
$I_H$	holding current	$V_D = 6 V$ $R_{GK} = \infty$	$T_{VJ} = 25^\circ C$		50	mA
$t_{gd}$	gate controlled delay time	$V_D = \frac{1}{2} V_{DRM}$ $I_G = 0.1 A; di_G/dt = 0.1 A/\mu s$	$T_{VJ} = 25^\circ C$		2	$\mu s$
$t_q$	turn-off time	$V_R = 100 V; I_T = 20 A; V_D = \frac{2}{3} V_{DRM}$ $T_{VJ} = 125^\circ C$ $di/dt = 10 A/\mu s; dv/dt = 20 V/\mu s; t_p = 200 \mu s$		150		$\mu s$

Package TO-220			Ratings			
Symbol	Definition	Conditions	min.	typ.	max.	Unit
$I_{RMS}$	RMS current	per terminal			35	A
$T_{stg}$	storage temperature		-55		150	°C
$T_{VJ}$	virtual junction temperature		-40		125	°C
Weight				2		g
$M_D$	mounting torque		0.4		0.6	Nm
$F_c$	mounting force with clip		20		60	N

### Product Marking



Ordering	Part Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	CS19-08ho1	CS19-08ho1	Tube	50	471038

Similar Part	Package	Voltage class
CS19-08ho1S	TO-263AB (D2Pak) (2)	800
CS19-12ho1	TO-220AB (3)	1200
CS19-12ho1S	TO-263AB (D2Pak) (2)	1200

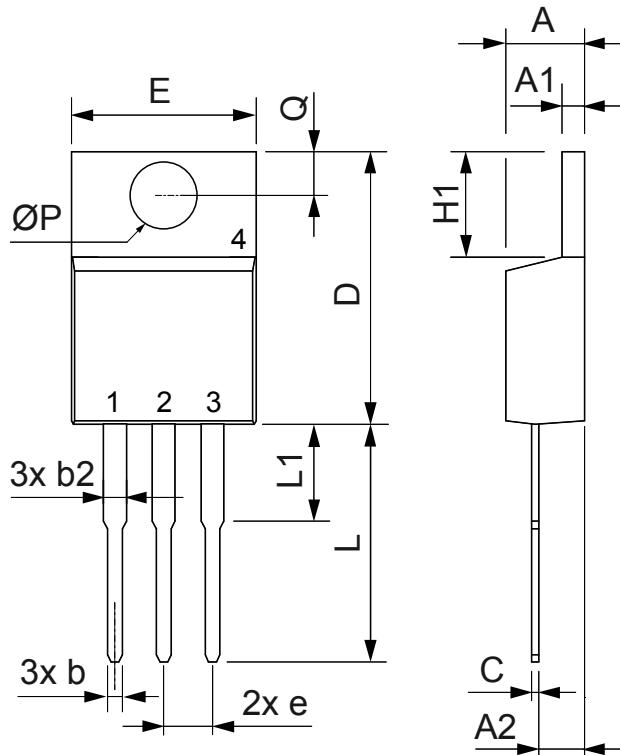
### Equivalent Circuits for Simulation

\* on die level

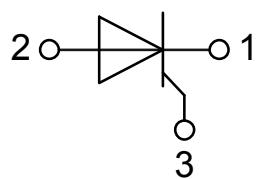
 $T_{VJ} = 125^\circ\text{C}$ 

	Thyristor		
$V_{0\max}$	threshold voltage	0.86	V
$R_{0\max}$	slope resistance *	19	mΩ

## Outlines TO-220



Dim.	Millimeter		Inches	
	Min.	Max.	Min.	Max.
A	4.32	4.82	0.170	0.190
A1	1.14	1.39	0.045	0.055
A2	2.29	2.79	0.090	0.110
b	0.64	1.01	0.025	0.040
b2	1.15	1.65	0.045	0.065
C	0.35	0.56	0.014	0.022
D	14.73	16.00	0.580	0.630
E	9.91	10.66	0.390	0.420
e	2.54	BSC	0.100	BSC
H1	5.85	6.85	0.230	0.270
L	12.70	13.97	0.500	0.550
L1	2.79	5.84	0.110	0.230
ØP	3.54	4.08	0.139	0.161
Q	2.54	3.18	0.100	0.125



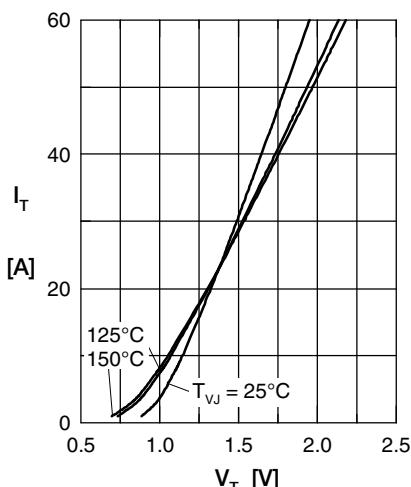
**Thyristor**

Fig. 1 Forward characteristics

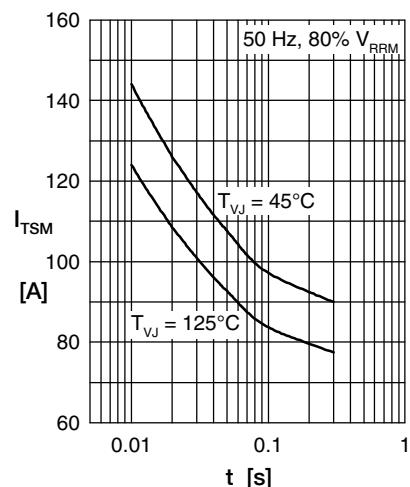


Fig. 2 Surge overload current

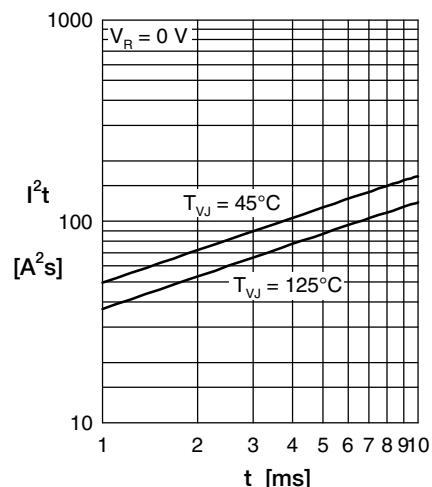
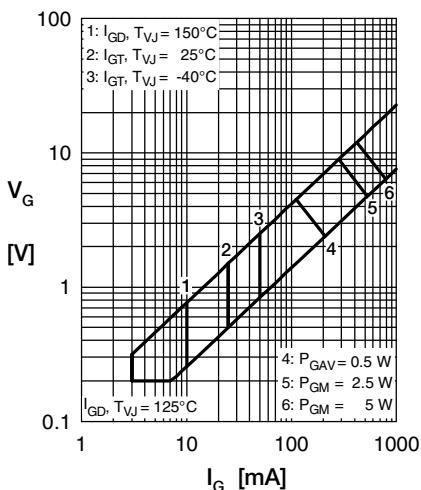
Fig. 3  $I^2t$  versus time (1-10 ms)

Fig. 4 Gate trigger characteristics

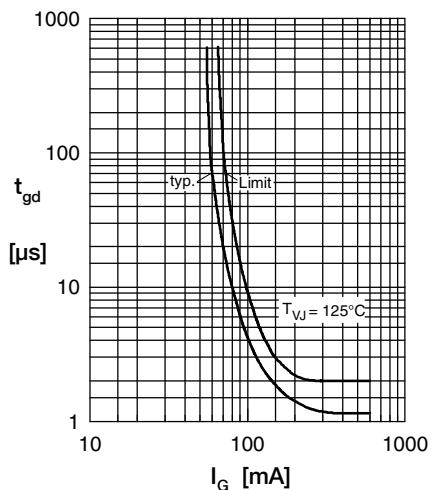


Fig. 5 Gate controlled delay time

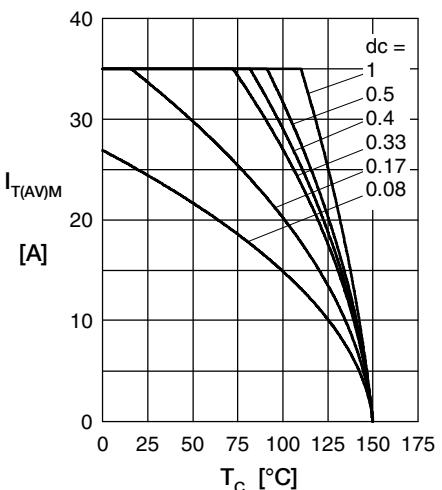


Fig. 6 Max. forward current at case temperature

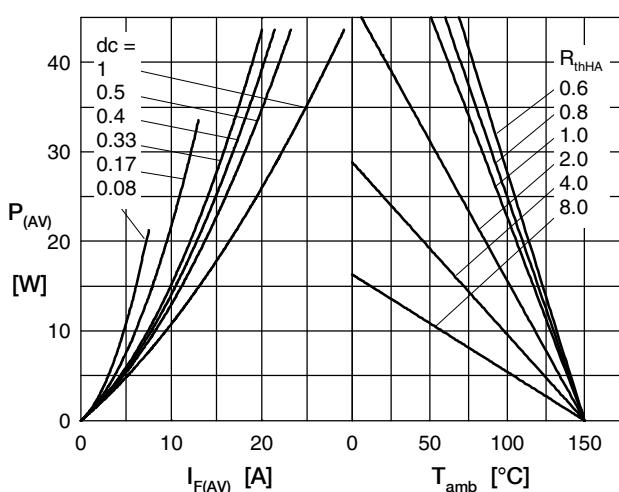
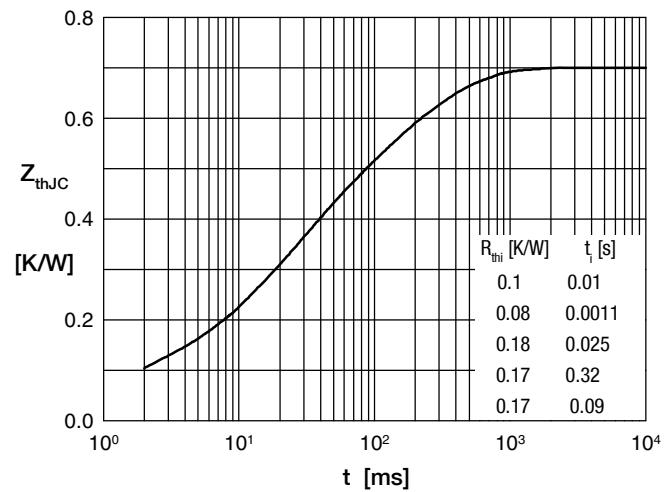
Fig. 7a Power dissipation versus direct output current  
Fig. 7b and ambient temperature

Fig. 8 Transient thermal impedance